PNP Epitaxial Silicon Transistor

Features

- Audio Power Amplifier
- 3 W Output Application

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

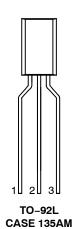
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	٧
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	- 5	٧
Collector Current	I _C	-2	Α
Junction Temperature	T_J	150	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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PIN CONNECTIONS

1. Emitter 2. Collector 3. Base

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 2 of this data sheet.

THERMAL CHARACTERISTICS (Note 1)

Symbol	Parameter	Value	Unit
P_{D}	Power Dissipation T _C = 25°C	1000	mW
	Derate Above T _A = 25°C	8.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	125	°C/W

^{1.} PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

ELECTRICAL CHARACTERISTICS (Note 2) Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -1 \text{ mA}, I_E = 0$	-50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{ mA}, I_B = 0$	-50			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -1 \text{ mA}, I_C = 0$	-5			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = -50 \text{ V}, I_{E} = 0$			-100	nA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = -5 \text{ V}, I_{C} = 0$			-100	nA
h _{FE1}	DC Current Gain	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$	120		240	
h _{FE2}		$V_{CE} = -2 \text{ V}, I_{C} = -1.5 \text{ A}$	40			
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = -1 A, I_B = -0.05 A$			-1.2	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -1 \text{ A}, I_B = -0.05 \text{ A}$			-0.5	V
C _{ob}	Output Capacitance	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		40		pF
f _T	Current Gain Bandwidth Product	$V_{CE} = -2 \text{ V}, I_{C} = -500 \text{ mA}$		100		MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method
KSA1281YTA	A1281 Y-	TO-92 3L	Ammo

^{2.} Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2.0%.

Typical Performance Characteristics

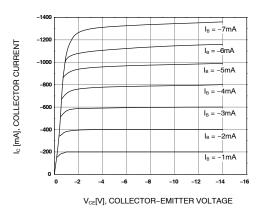


Figure 1. Static Characteristic

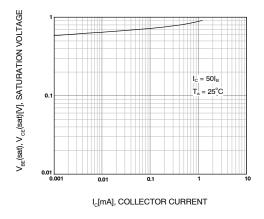


Figure 2. Base-Emitter Saturation Voltage

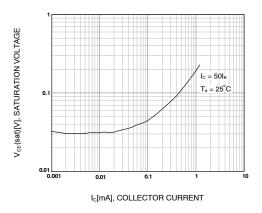


Figure 3. Collector-Emitter Saturation Voltage

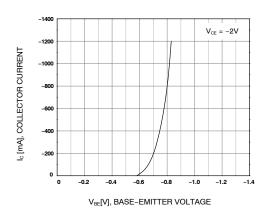


Figure 4. Base-Emitter On Voltage

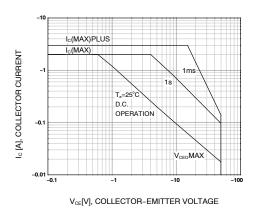


Figure 5. Safe Operating Area

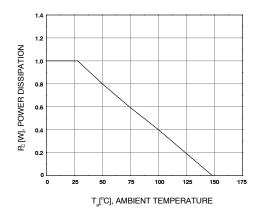
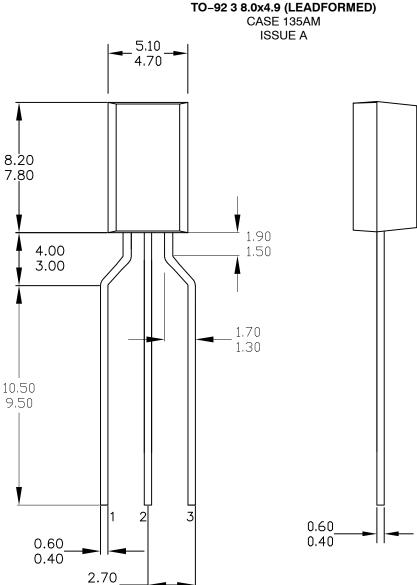
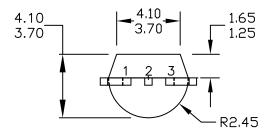


Figure 6. Power Derating

PACKAGE DIMENSIONS





2.30

NOTES: UNLESS OTHERWISE SPECIFIED

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